

STEREO AUDIO AMPLIFIER

1 FEATURES

- DUAL OR BRIDGE CONNECTION MODES
- FEW EXTERNAL COMPONENTS
- SUPPLY VOLTAGE DOWN TO 3V
- HIGH CHANNEL SEPARATION
- VERY LOW SWITCH ON/OFF NOISE
- MAX GAIN OF 45dB WITH ADJUST EXTERNAL RESISTOR
- SOFT CLIPPING
- THERMAL PROTECTION
- $3V < V_{CC} < 15V$
- $P = 2 \cdot 1W, V_{CC} = 6V, R_L = 4\Omega$
- $P = 2 \cdot 2.3W, V_{CC} = 9V, R_L = 4\Omega$
- $P = 2 \cdot 0.1W, V_{CC} = 3V, R_L = 4\Omega$

Figure 1. Package

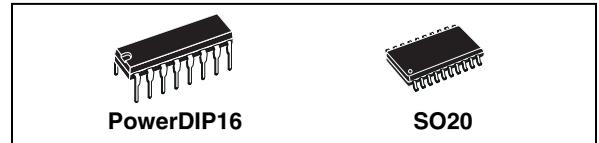


Table 1. Order Codes

| Part Number | Package |
|---------------|---------------------|
| TEA2025B | PowerDIP 12+2+2 |
| TEA2025D | SO20 12+4+4 |
| TEA2025D013TR | SO16 in Tape & Reel |

2 DESCRIPTION

The TEA2025B/D is a monolithic integrated circuit in 12+2+2 Powerdip and 12+4+4 SO, intended for use as dual or bridge power audio amplifier portable radio cassette players.

Figure 2. Block Diagram

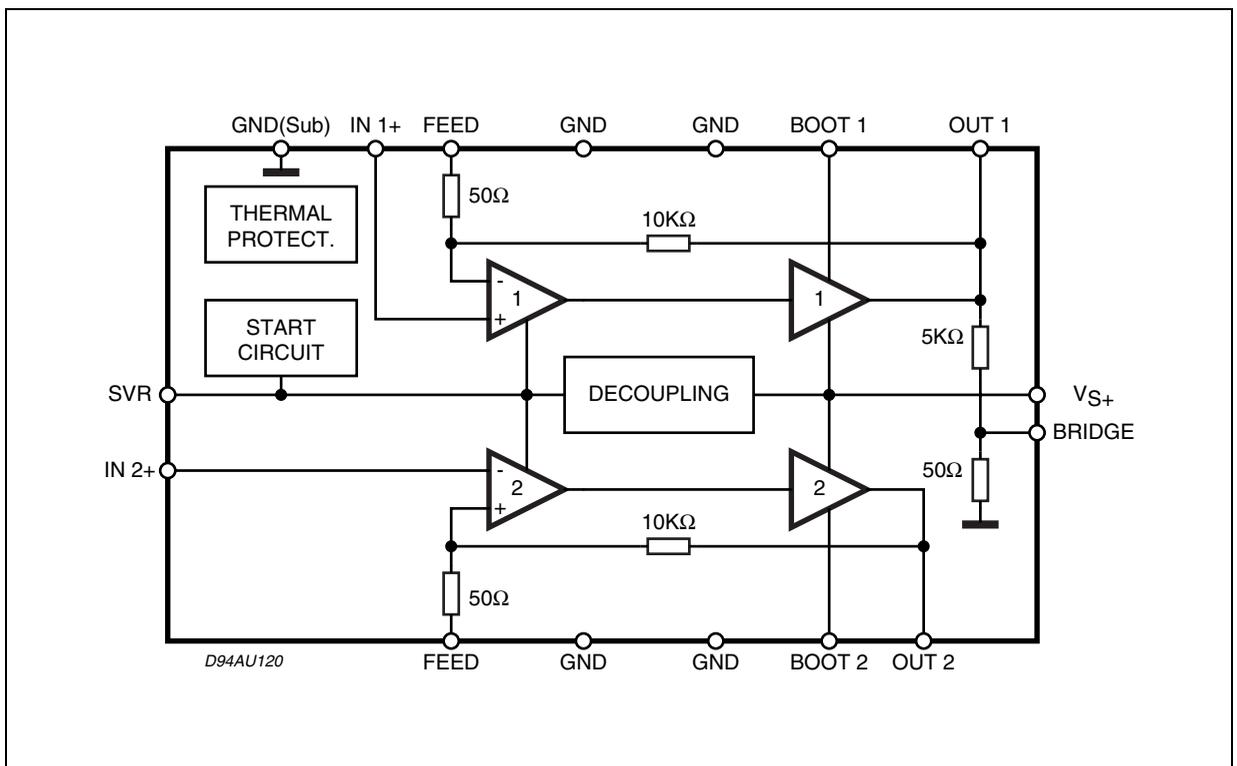
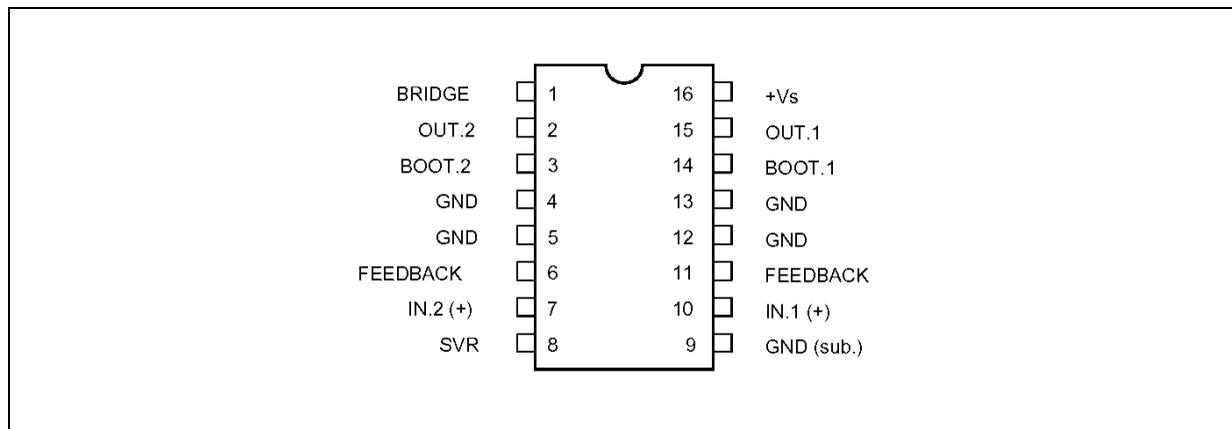
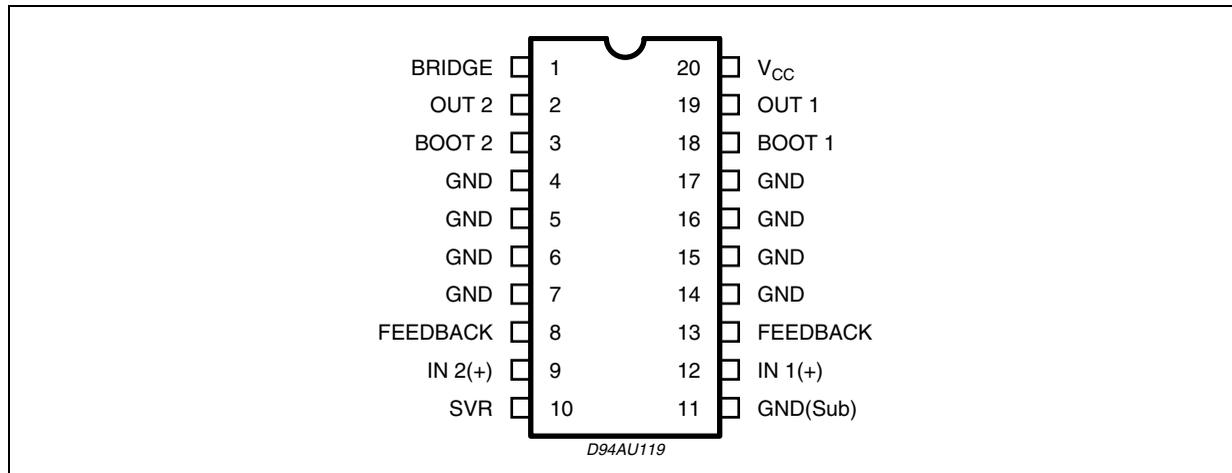


Table 2. Absolute Maximum Ratings

| Symbol | Parameter | Value | Unit |
|------------------|----------------------|-------|------|
| V _S | Supply Voltage | 15 | V |
| I _O | Output Peak Current | 1.5 | A |
| T _J | Junction Temperature | 150 | °C |
| T _{stg} | Storage Temperature | 150 | °C |

Figure 3. PIN CONNECTION POWERDIP12+2+2**Figure 4. PIN CONNECTION SO12+4+4****Table 3. Thermal Data**

| Symbol | Description | | SO 12+4+4 ⁽¹⁾ | PDIP 12+2+2 ⁽²⁾ | Unit |
|------------------------|-------------------------------------|-----|--------------------------|----------------------------|------|
| R _{th j-case} | Thermal Resistance Junction-case | Max | 15 | 15 | °C/W |
| R _{th j-amb} | Thermal Resistance Junction-ambient | Max | 65 | 60 | °C/W |

Note: 1. The R_{th j-amb} is measured with 4sq cm copper area heatsink

2. The R_{th j-amb} is measured on devices bonded on a 10 x 5 x 0.15cm glass-epoxy substrate with a 35µm thick copper surface of 5 cm²

Table 4. Electrical Characteristics ($T_{amb} = 25^{\circ}\text{C}$, $V_{CC} = 9\text{V}$, Stereo unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit | |
|--------------|--------------------------|--|----------------|------------|---------|------------|---|
| V_S | Supply Voltage | | 3 | | 12 | V | |
| I_Q | Quiescent Current | | | 35 | 50 | mA | |
| V_O | Quiescent Output Voltage | | | 4.5 | | V | |
| A_V | Voltage Gain | Stereo | 43 | 45 | 47 | dB | |
| | | Bridge | 49 | 51 | 53 | dB | |
| ΔA_V | Voltage Gain Difference | | | | ± 1 | dB | |
| R_i | Input Impedance | | | 30 | | K Ω | |
| P_O | Output Power (d = 10%) | Stereo 8 (per channel) | 9V 4 Ω | 1.7 | 2.3 | | W |
| | | | 9V 8 Ω | | 1.3 | | W |
| | | | 6V 4 Ω | 0.7 | 1 | | W |
| | | | 6V 8 Ω | | 0.6 | | W |
| | | | 6V 16 Ω | | 0.25 | | W |
| | | | 6V 32 Ω | | 0.13 | | W |
| | | | 3V 4 Ω | | 0.1 | | W |
| | | | 3V 32 Ω | | 0.02 | | W |
| | | Bridge | 12V 8 Ω | | 2.4 | | W |
| | | | 9V 8 Ω | | 4.7 | | W |
| | | | 6V 4 Ω | | 2.8 | | W |
| | | | 6V 8 Ω | | 1.5 | | W |
| | | | 3V 16 Ω | | 0.18 | | W |
| | | | 3V 32 Ω | | 0.06 | | W |
| d | Distortion | $V_S = 9\text{V}$; $R_L = 4\Omega$ | | 0.3 0.5 | 1.5 | % | |
| SVR | Supply Voltage Rejection | $f = 100\text{Hz}$, $V_R = 0.5\text{V}$, $R_g = 0$ | 40 | 46 | | dB | |
| $E_{N(IN)}$ | Input Noise Voltage | $R_G = 0$ | | 1.5 | 3 | mV | |
| | | $R_G = 10\ 4\Omega$ | | 3 | 6 | mV | |
| CT | Cross-Talk | $f = 1\text{KHz}$, $R_g = 10\text{K}\Omega$ | 40 | 52 | | dB | |

Table 5.

| Term. N° (PDIP) | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 | 16 |
|-----------------|------|-----|-----|---|---|-----|------|-----|---|------|-----|----|----|-----|-----|----|
| DC VOLT (V) | 0.04 | 4.5 | 8.9 | 0 | 0 | 0.6 | 0.04 | 8.5 | 0 | 0.04 | 0.6 | 0 | 0 | 8.9 | 4.5 | 9 |

Figure 5. Bridge Application (Powerdip)

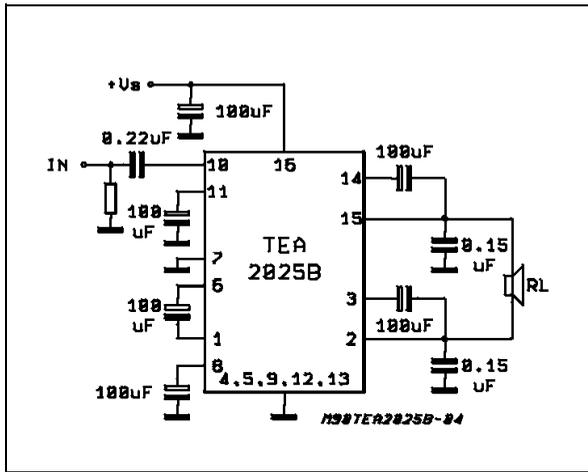


Figure 8. Output Voltage vs. Supply Voltage

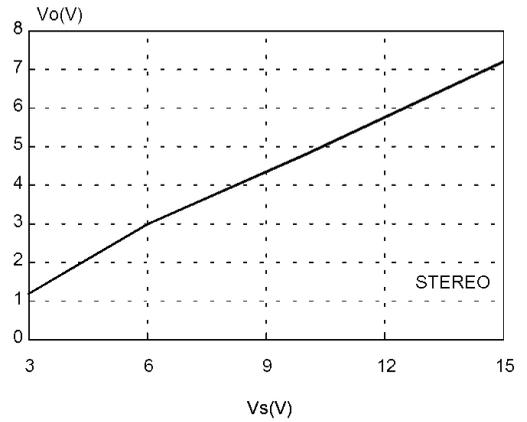


Figure 6. Stereo Application (Powerdip)

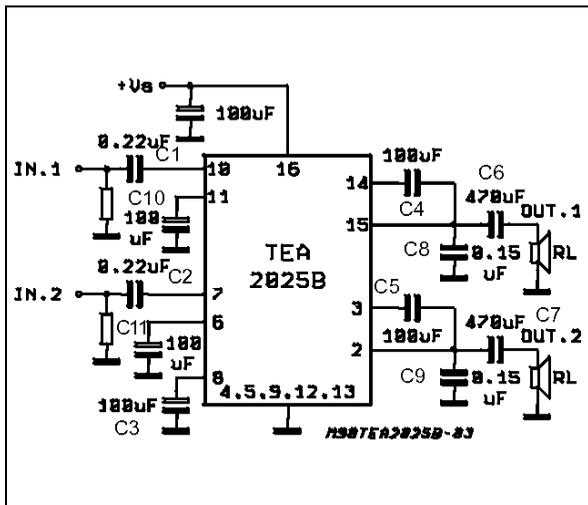


Figure 9. Output Power vs. Supply Voltage (THD = 10%, f = 1KHz)

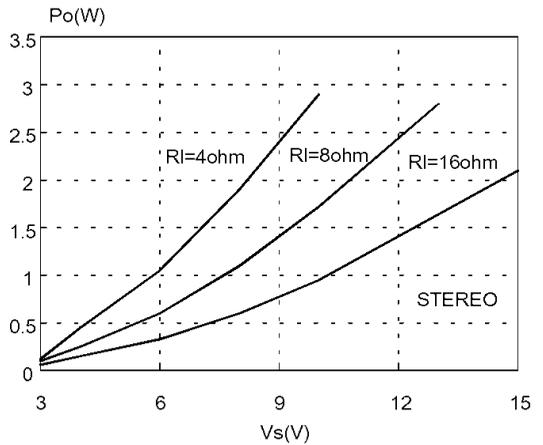


Figure 7. Supply Current vs. Supply Voltage (RL = 4Ω)

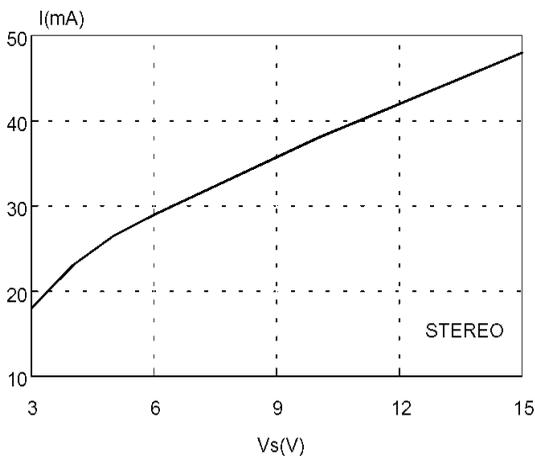
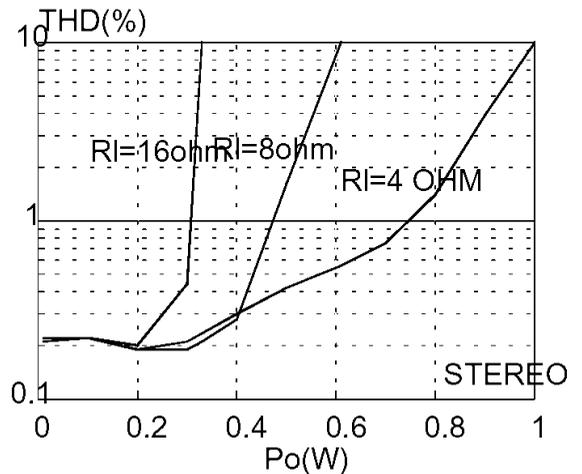


Figure 10. THD versus Output Power (f = 1KHz, Vs = 6V)



3 APPLICATION INFORMATION

3.1 Input Capacitor

Input capacitor is PNP type allowing source to be referenced to ground.

In this way no input coupling capacitor is required. However, a series capacitor (0.22 μ F) to the input side can be useful in case of noise due to variable resistor contact.

3.2 Bootstrap

The bootstrap connection allows to increase the output swing.

The suggested value for the bootstrap capacitors (100 μ F) avoids a reduction of the output signal also at low frequencies and low supply voltages.

3.3 Voltage Gain Adjust

3.3.1 STEREO MODE

The voltage gain is determined by on-chip resistors R1 and R2 together with the external RfC1 series connected between pin 6 (11) and ground. The frequency response is given approximated

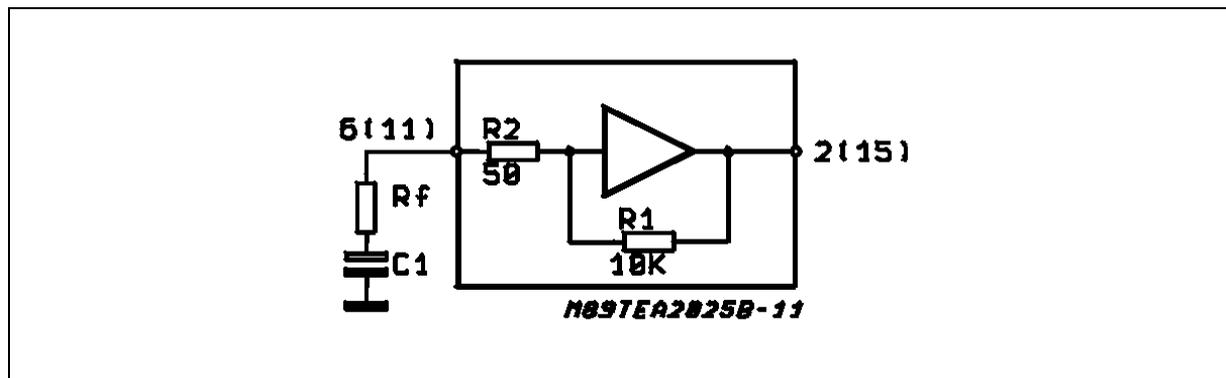
$$\frac{V_{OUT}}{V_{IN}} = \frac{R1}{Rf + R2 + \frac{1}{JWC1}}$$

With Rf=0, C1=100 μ F, the gain results 46 dB with pole at f=32 Hz.

THE purpose of Rf is to reduce the gain. It is recommended to not reduce it under 36 dB.

3.3.2 BRIDGE MODE

Figure 11.



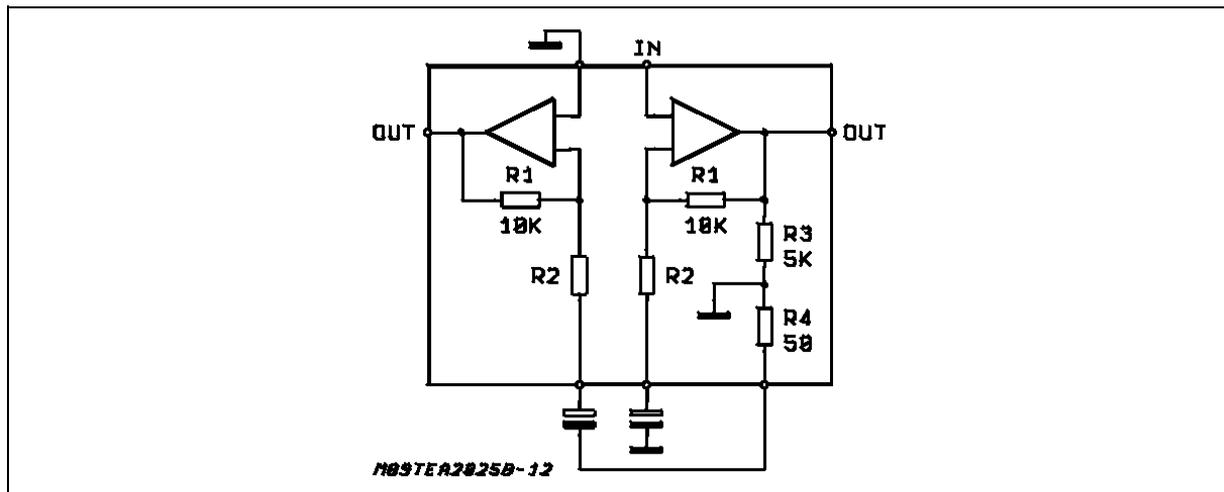
The bridge configuration is realized very easily thanks to an internal voltage divider which provides (at pin 1) the CH 1 output signal after reduction.

It is enough to connect pin 6 (inverting input of CH 2) with a capacitor to pin 1 and to connect to ground the pin 7. The total gain of the bridge is given by:

$$\frac{V_{OUT}}{V_{IN}} = \frac{R1}{Rf + R2 + \frac{1}{JWC1}} \left(1 + \frac{R3}{R4} \frac{R1}{R2 + R4 + \frac{1}{JWC1}} \right)$$

and with the suggested values (C1 = C2 = 100 μ F, Rf= 0) means: Gv = 52 dB with first pole at f = 32 Hz

Figure 12.



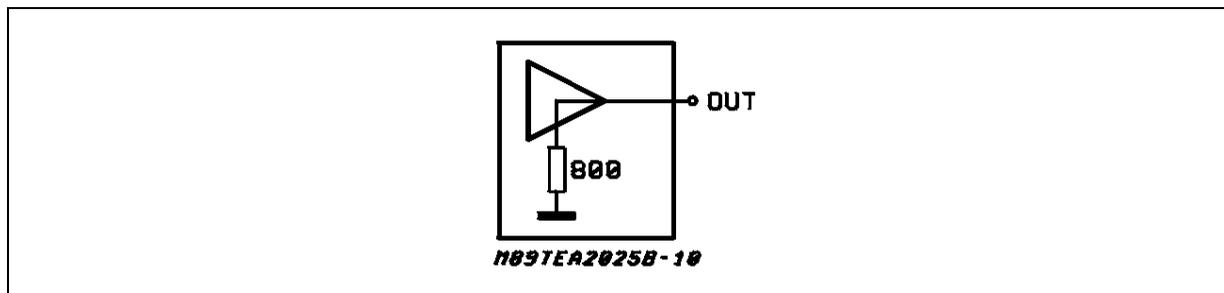
3.4 Output Capacitors.

The low cut off frequency due to output capacitor depending on the load is given by: $F_L = \frac{1}{2\pi C_{OUT} \cdot R_L}$ with C_{OUT} 470mF and $R_L = 4$ ohm it means $F_L = 80$ Hz.

3.5 Pop Noise

Most amplifiers similar to TEA 2025B need external resistors between DC outputs and ground in order to optimize the pop on/off performance and crossover distortion.

Figure 13.



The TEA 2025B solution allows to save components because of such resistors (800 ohm) are included into the chip.

3.6 Stability

A good layout is recommended in order to avoid oscillations.

Generally the designer must pay attention on the following points:

- Short wires of components and short connections.
- No ground loops.
- Bypass of supply voltage with capacitors as nearest as possible to the supply I.C.pin. The low value (poliester) capacitors must have good temperature and frequency characteristics.
- No sockets.

the heatsink can have a smaller factor of safety compared with that of a conventional circuit. There is no device damage in the case of excessive junction temperature: all that happens is that PO (and

therefore P_{tot}) and I_d are reduced.

4 APPLICATION SUGGESTION

The recommended values of the components are those shown on stereo application circuit of Fig. 6 different values can be used, the following table can help the designer.

Table 6.

| COMPONENT | RECOMMENDED VALUE | PURPOSE | LARGER THAN | SMALLER THAN |
|-----------|-------------------|---|-------------|---|
| C1,C2 | 0.22 μ F | INPUT DC DECOUPLING IN CASE OF SLIDER CONTACT NOISE OF VARIABLE RESISTOR | | |
| C3 | 100 μ F | RIPPLE REJECTON | | DEGRADATION OF SVR, INCREASE OF AT LOW FREQUENCY AND LOW VOLTAGE |
| C4,C5 | 100 μ F | BOOTSTRAP | | |
| C6,C7 | 470 μ F | OUTPUT DC DECOUPLING | | INCREASE OF LOW FREQUENCY CUTOFF |
| C8,C9 | 0.15 μ F | FREQUENCY STABILITY | | DANGEROF OSCILLATIONS |
| C10, C11 | 100 μ F | INVERTING INPUT DC DECOUPLING | | INCREASE OFLOW FREQUENCYCUTOFF |

5 PACKAGE MECHANICAL DATA

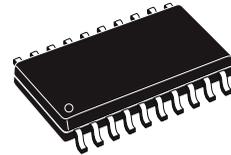
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Figure 14. SO20 Mechanical Data & Package Dimensions

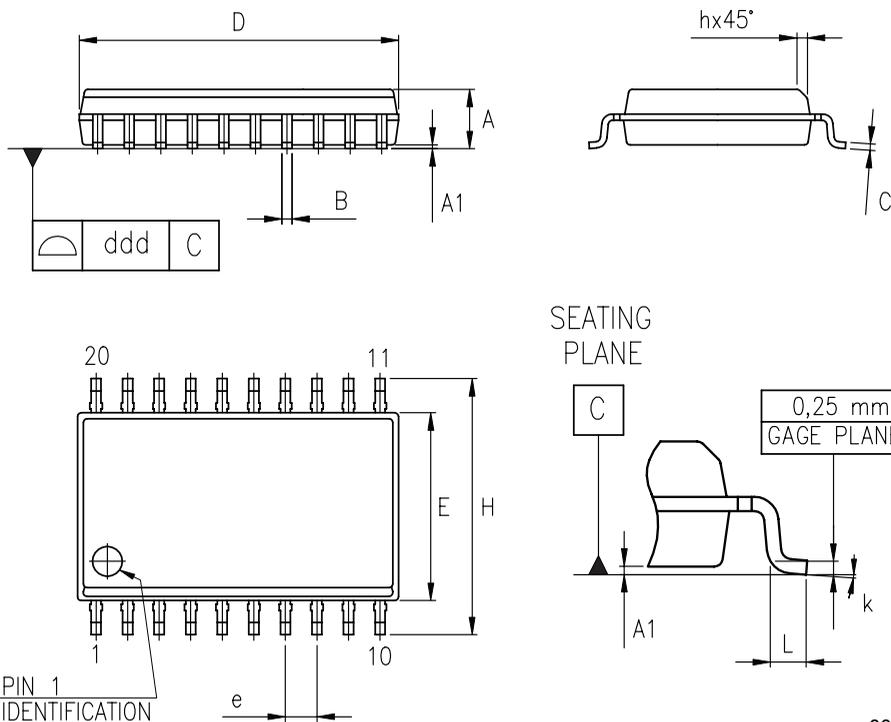
| DIM. | mm | | | inch | | |
|-------|----------------------|------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 2.35 | | 2.65 | 0.093 | | 0.104 |
| A1 | 0.10 | | 0.30 | 0.004 | | 0.012 |
| B | 0.33 | | 0.51 | 0.013 | | 0.200 |
| C | 0.23 | | 0.32 | 0.009 | | 0.013 |
| D (1) | 12.60 | | 13.00 | 0.496 | | 0.512 |
| E | 7.40 | | 7.60 | 0.291 | | 0.299 |
| e | | 1.27 | | | 0.050 | |
| H | 10.0 | | 10.65 | 0.394 | | 0.419 |
| h | 0.25 | | 0.75 | 0.010 | | 0.030 |
| L | 0.40 | | 1.27 | 0.016 | | 0.050 |
| k | 0° (min.), 8° (max.) | | | | | |
| ddd | | | 0.10 | | | 0.004 |

(1) "D" dimension does not include mold flash, protusions or gate burrs. Mold flash, protusions or gate burrs shall not exceed 0.15mm per side.

OUTLINE AND MECHANICAL DATA



SO20

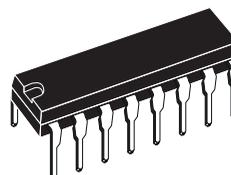


0016022 D

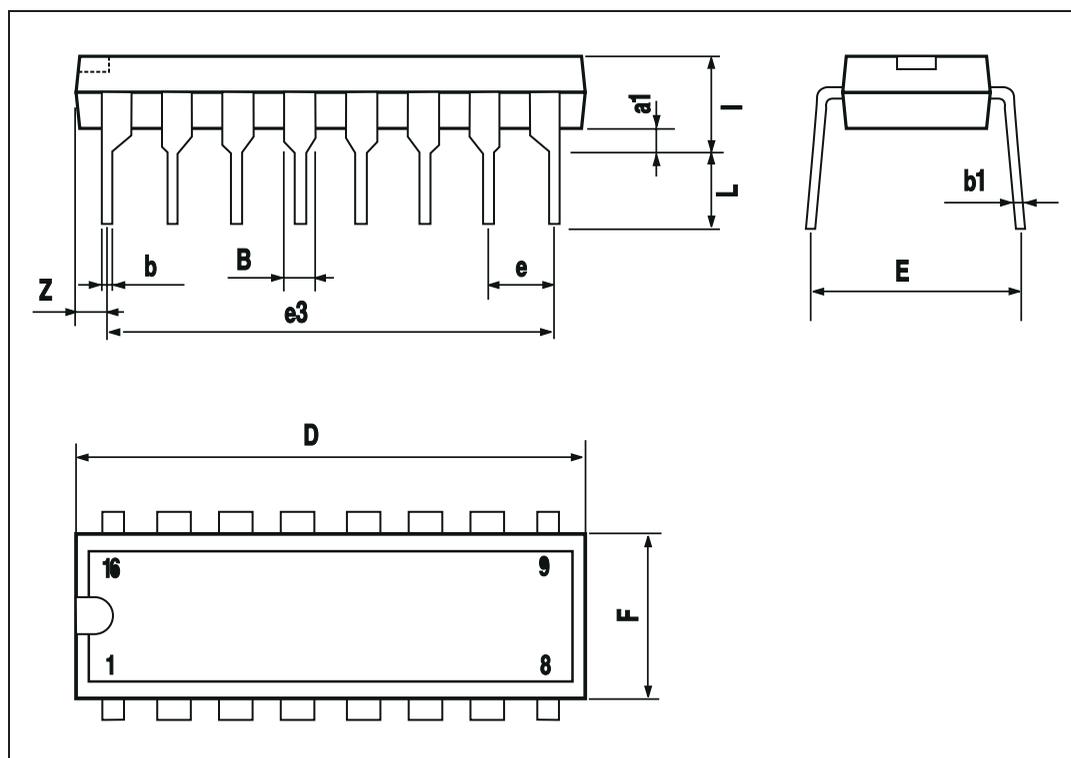
Figure 15. DIP16 Mechanical Data & Package Dimensions

| DIM. | mm | | | inch | | |
|------|------|-------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| a1 | 0.51 | | | 0.020 | | |
| B | 0.77 | | 1.65 | 0.030 | | 0.065 |
| b | | 0.5 | | | 0.020 | |
| b1 | | 0.25 | | | 0.010 | |
| D | | | 20 | | | 0.787 |
| E | | 8.5 | | | 0.335 | |
| e | | 2.54 | | | 0.100 | |
| e3 | | 17.78 | | | 0.700 | |
| F | | | 7.1 | | | 0.280 |
| I | | | 5.1 | | | 0.201 |
| L | | 3.3 | | | 0.130 | |
| Z | | | 1.27 | | | 0.050 |

OUTLINE AND MECHANICAL DATA



DIP16



6 REVISION HISTORY

Table 7. Revision History

| Date | Revision | Description of Changes |
|----------------|----------|--|
| September 2003 | 2 | Updates not recorded |
| 30-Apr-2010 | 3 | Updated title and added environmental compliance statement for package |

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